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Passivation Layer by SiC Thin Film Deposition for High Efficiency Solar Cells MAHDI HAGHZEDEH, ECE U. Mass Lowell, DANIEL SCHMIDT, Plastics Eng U. Mass Lowell, JOEL THERRIEN, ECE U. Mass Lowell - Deposition of a polymer derived SiC thin film as a novel, chemically and physically stable passivation layer to enhance the efficiency of solar cells by way of reducing surface recombination was studied. Starfire Matrix Polymer number 10 (SMP-10) is used to produce thin films of SiC on ion implanted silicon wafers. To ascertain the best method to deposit, three methods were tested: spin coating, spray coating, and dip coating are used. Various concentrations of SMP-10 diluted in xylene as an appropriate solvent are examined. To test the films, a contactless inductive coupling method is used. The thinner layers of SiC are grown by a lower percentage of SMP-10 (5%), higher spin speed in spin coating (3000 RPM), and lower pulling out speed in dip coating (50 mm/minute). All of the methods yield controllable, repeatable, and uniform thin films. Although eliminating oxygen as an impurity in the passivation layer remains a challenge, the described approach has promise as a simple, low-cost passivation layers for higher efficiency solar cells.

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